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Application Number	10/623,375 (Patent No. 6,955,719)	
Filing Date	07-18-2003	
First Named Inventor	Vladimir Dmitriev	
Title	Manufacturing Methods for Semicondu	
Art Unit	1722	
Examiner Name	SONG, MATTHEW J	
Attorney Docket Number	TDI-008-US1	

I hereby revoke all previous powers of attorney given in the above-identified application.						
I hereby appoint:						
Practitioners associated with the Customer Number:	23410					
OR						
Practitioner(s) named below:						
Name	Registration Number					
as my/our attorney(s) or agent(s) to prosecute the application identified a Trademark Office connected therewith.	above, and to transact all business in the United States Patent and					
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Applicant/Inventor.						
Assignee of record of the entire interest. See 37 CFR 3.71.						
Assignee of record of the entire interest. See 37 CFR 3.71. Statement under 37 CFR 3.73(b) is enclosed. (Form PTO/SB/96)						
SIGNATURE of Applicant	t or Assignee of Record					
Signature [Please see signed document attached]	Date January 17, 2007					
e Vladimir Dmitriev Telephone						
tle and Company President, Technologies and Devices International, Inc.						
NOTE: Signatures of all the inventors or assignees of record of the entire interest of signature is required, see below*.	or their representative(s) are required. Submit multiple forms if more than one					
*Total offorms are submitted.						

This collection of information is required by 37 CFR 131, 132 and 133. The information is required to obtain or retain a benefit by the public which is to file (and by the USFTO to process) an application. Confidentiatily is ownered by 36 USE, 122 and 37 CFR 111 and 114. This collection is estimated to take 3 minutes to complete, including gathering, preparing, and submitting the completed application from to the USFTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burders, should be sent to the Chimomation Office, U.S. Potent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Mexandris, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O., Box 1450, Mexandris, VA 22313-1450.

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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POWER OF ATTORNEY (REVOCATION OF PRIOR POWERS) AND PROSECUTION BY ASSIGNEE UNDER 37 C.F.R. § 3.71

Sir:

TECHNOLOGIES AND DEVICES INTERNATIONAL, INC., the assignee of the entire right, title and interest of the patents and patent applications listed below, under 37 C.F.R. § 3.71 hereby revokes all powers of attorneys previously given in the below-identified patent applications and hereby appoints all attorneys associated with:

Customer Number

23410

PATENT TRADEMARK OFFICE

with full powers of substitution and revocation, to prosecute this application and transact all matters in the United States Patent and Trademark Office, and in countries other than the United States, and to do all things necessary or appropriate therefore before any competent International Authorities in connection with any international patent application(s) corresponding to the above-identified application, said appointment to be to the exclusion of the inventors and their attorneys in accordance with the provisions of 37 C.F.R. § 3.71.

Correspondence Address

Please change the correspondence address for the below-identified patent applications to the customer number 23410, and direct all written communications relative to such applications to:

> Gary D. Lucck Vista IP Law Group LLP 2040 Main Street, 9th Floor Irvine, California 92614

Please direct all telephone communications to Gary D. Lueck at (714) 449-8433.

Patent Applications and Patents:

Vista Docket No.	Tirle	Serial No.	Patent No.
		(Filing Date)	(Issue Date)
TDI-005-USI M	Method and Apparatus for Fabricating Crack-Free Group III Nitride Semiconductor Materials	10/778,633	
		(2/13/04)	
TDI-005-US2	Method and Apparatus for Fabricating Crack-Free Group III Nitride Semiconductor Materials	11/483,455	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,
		(7/10/06)	
TDI-005-US1	HVPE Apparatus For Simultaneously Producing Multiple Wafers During a Single Epitaxial Growth Run	11/173,039	
		(7/1/05)	
TDI-006-US2	Method for Simultaneously Producing Multiple Wafers During a Single Epitaxial Growth Run	11/173,193	
		(7/1/05)	
	Method of Epitaxially Growing Device Structures With Sharp Layer Interfaces Utilizing HVPE	10/109,988	6,573,164
		(3/28/02)	(6/3/03)
	Apparatus for Epitaxially Growing Semiconductor Device Structures With Sharp Layer Interfaces Using HVPE	10/113,222	
	, and a state of the state of t	(3/28/02)	
TDI-007-US3	Apparatus for Epitaxially Growing Semiconductor Device Structures With Submicron Group III Nitride Layer	10/109,317	6,706,119
	Utilizing HVPE	(3/28/02)	(3/16/04)
TDI-007-US4	Method of Epitaxially Growing Submicron Group III Nitride Layer Utilizing HVPE	10/112,277	6,656,272
	State of the state	(3/28/02)	(12/2/03)
TDI-007-US5	Method of Epitaxially Growing Device Structures With Submicron Group III Nitride Layers Utilizing HVPE	10/113,692	6,660,083
	three Edycts Othering 11112	(3/28/02)	(12/9/03)
TDI-008-US1	Manufacturing Methods for Semiconductor Devices With Multiple III-V Material Layers	10/623,375	6.955,719
	111 - 11100101 211,013	(7/18/03)	(10/18/05)
TDI-011-US3	Reactor for Extended Growth Duration of Gallium Containing Single Crystals	10/632,736	
		(8.1/03)	

Power of Attorney Technologies and Devices International, Inc.

I, the undersigned, declare that I have reviewed copies of the documentary evidence establishing chain of title to the patent applications identified above from the inventor(s) to the assignee.

To the best of the undersigned's knowledge and belief, title is in the assignce identified above. Furthermore, the undersigned is empowered to sign this document on behalf of the assignce.

Dated: Jan. 17,07

TECHNOLOGIES AND DEVICES INTERNATIONAL, INC.

vame Dull

Title: President

Address: 12214 Plum Orchard Drive Silver Spring, MD 20904